



### 20V Complementary Enhancement Mode MOSFET

Voltage

20 / -20V

Current

4.1 /-3.1A

### **Features**

- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

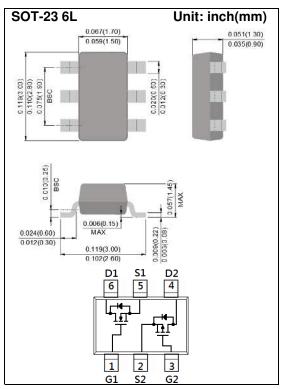
### **Mechanical Data**

• Case: SOT-23 6L Package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0005 ounces, 0.014 grams

Marking: SC1



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	N-Ch LIMIT P-Ch LIMIT		UNITS	
Drain-Source Voltage		V <sub>DS</sub>	20	-20	V
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 12	<u>+</u> 12	V
Continuous Drain Current		ID	4.1	-3.1	Α
Pulsed Drain Current <sup>(Note 4)</sup>		I <sub>DM</sub>	16.4	-12.4	Α
B Discission	T <sub>a</sub> =25°C	Б	1.25		W
Power Dissipation	Derate above 25°C	P <sub>D</sub>	10		mW/°C
Operating Junction and Storage Temperature Range		$T_{J}, T_{STG}$	-55~150		°C
Typical Thermal Resistance - Junction to Ambient <sup>(Note 3)</sup>		R <sub>θJA</sub>	100		°C/W





## N-Channel Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	20	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	0.4	0.66	1.2	V
Drain-Source On-State Resistance		V <sub>GS</sub> =4.5V, I <sub>D</sub> =4.1A	-	41	56	mΩ
	R <sub>DS(on)</sub>	V <sub>GS</sub> =2.5V, I <sub>D</sub> =2.8A	-	50	68	
		V <sub>GS</sub> =1.8V, I <sub>D</sub> =1.5A	-	66	95	
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	Igss	V <sub>GS=+</sub> 12V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic <sup>(Note 5)</sup>						
Total Gate Charge	Qg	V <sub>DS</sub> =10V, I <sub>D</sub> =4.1A, V <sub>GS</sub> =4.5V <sup>(Note 1,2)</sup>	-	4.6	-	nC
Gate-Source Charge	Qgs		-	0.8	-	
Gate-Drain Charge	$Q_{gd}$	VGS=4.5 V (1888 1)=7	-	1	-	
Input Capacitance	Ciss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1.0MHZ	-	350	-	pF
Output Capacitance	Coss		-	40	-	
Reverse Transfer Capacitance	Crss		-	29	-	
Turn-On Delay Time	td <sub>(on)</sub>	\/ 10\/ L 41A	-	4	-	
Turn-On Rise Time	tr	$\begin{array}{l} V_{\text{DD}}{=}10\text{V, I}_{\text{D}}{=}4.1\text{A,} \\ V_{\text{GS}}{=}4.5\text{V,} \\ R_{\text{G}}{=}6\Omega^{(\text{Note 1,2})} \end{array}$	-	47	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	18	-	
Turn-Off Fall Time	tf		-	10	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	1.5	Α
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V	-	0.75	1.2	V

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Reja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing





### P-Channel Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-20	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-0.4	-0.71	-1.2	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-3.1A	-	84	100	mΩ
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-2.0A	-	104	135	
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-1.1A	-	134	190	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V	-	-	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic <sup>(Note 5)</sup>			_			_
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-10V, I <sub>D</sub> =-3.1A, V <sub>GS</sub> =-4.5V <sup>(Note 1,2)</sup>	-	5.4	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	0.7	-	
Gate-Drain Charge	$Q_{gd}$	VGS=-4.5 V(1000 1,2)	-	1.3	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V, f=1.0MHZ	-	416	-	pF
Output Capacitance	Coss		-	43	-	
Reverse Transfer Capacitance	Crss		-	32	-	
Turn-On Delay Time	td <sub>(on)</sub>	V 40V I 04A	-	4	-	
Turn-On Rise Time	tr	$V_{DD}$ =-10V, $I_{D}$ =-3.1A, $V_{GS}$ =-4.5V, $R_{G}$ =6 $\Omega^{(Note 1,2)}$	-	27	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	78	-	
Turn-Off Fall Time	tf	MG=012(Note 1,2)	-	45	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	-1.5	Α
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =-1.0A, V <sub>GS</sub> =0V	-	-0.8	-1.2	V

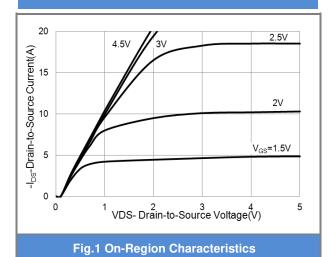
#### NOTES:

- 1. Pulse width < 300us, Duty cycle < 2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. ROJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





### N-Channel TYPICAL CHARACTERISTIC CURVES



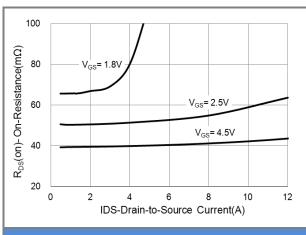
-I<sub>DS</sub>-Drain-to-Source Current(A) 9 6 T<sub>J</sub>=125℃ T,=25℃ 3 0 0 1.2 2.4 3 VGS-Gate-to-Source Voltage(V)

15

12

V<sub>DS</sub>=5V

Fig.2 Transfer Characteristics





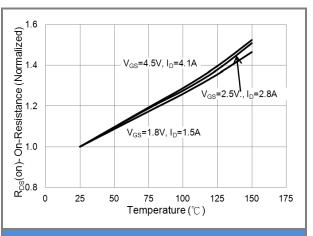
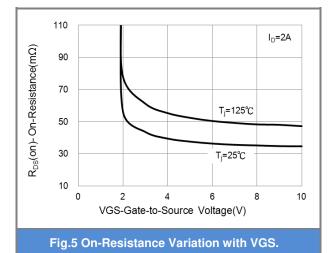
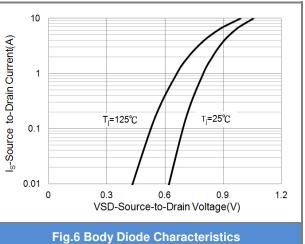


Fig.4 On-Resistance vs. Junction temperature









### **N-Channel TYPICAL CHARACTERISTIC CURVES**

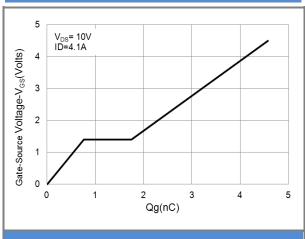


Fig.7 Gate-Charge Characteristics

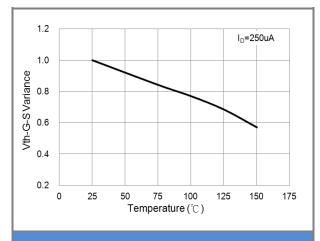


Fig.8 Threshold Voltage Variation with Temperature.

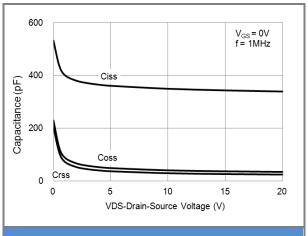


Fig.9 Capacitance vs. Drain-Source Voltage.





#### P-Channel TYPICAL CHARACTERISTIC CURVES

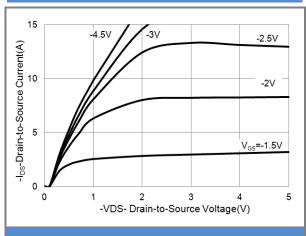


Fig.1 On-Region Characteristics

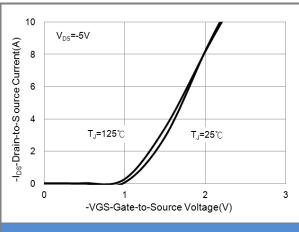


Fig.2 Transfer Characteristics

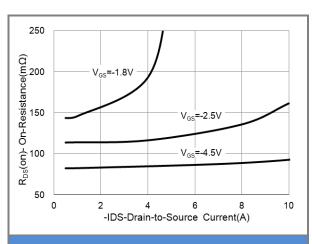


Fig.3 On-Resistance vs. Drain Current

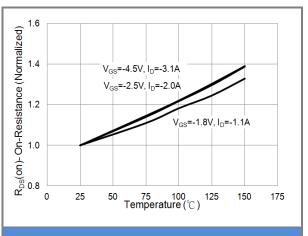
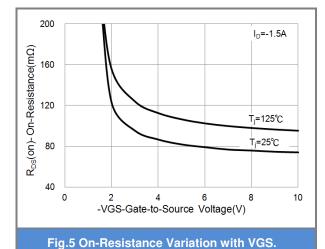
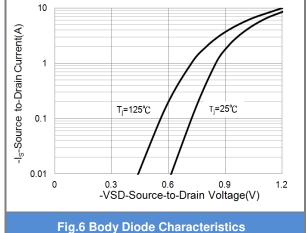


Fig.4 On-Resistance vs. Junction temperature









### P-Channel TYPICAL CHARACTERISTIC CURVES

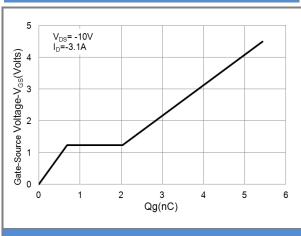


Fig.7 Gate-Charge Characteristics

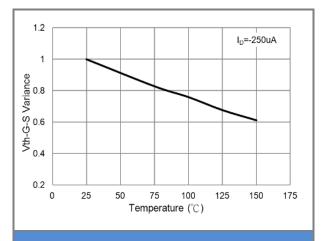


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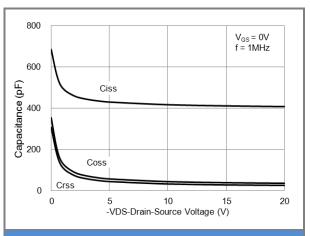


Fig.9 Threshold Voltage Variation with Temperature.

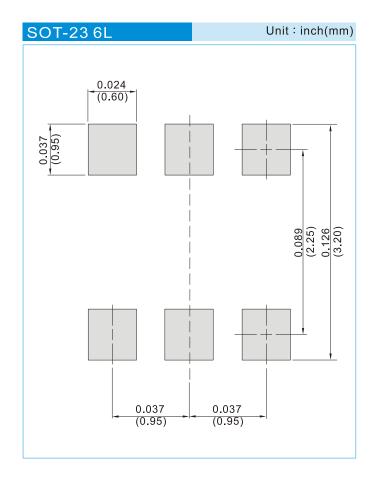




### PART NO. PACKING CODE VERSION

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJS6601_S1_00001	SOT-23 6L	3K pcs / 7" reel	SC1	Halogen free RoHS compliant
PJS6601_S2_00001	SOT-23 6L	10K pcs / 13" reel	SC1	Halogen free RoHS compliant

## **MOUNTING PAD LAYOUT**







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